IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re U.S. Patent Application of	, 7	H-31 Tos Anns	J 76997
TAKAGAWA et al.)	5130/0	
Application Number: To Be Assigned)		
)		

Honorable Assistant Commissioner for Patents Washington, D.C. 20231

SEMICONDUCTOR DEVICE

Filed Concurrently Herewith

INFORMATION DISCLOSURE STATEMENT

Sir:

For:

Pursuant to 37 C.F.R. §§ 1.56 and 1.97, this Information Disclosure Statement is submitted in the above-identified patent application. A listing of documents to be published on the face of any patent granted from this application is submitted herewith on Form PTO-1449. Any other documents or information submitted for consideration by the Examiner are listed in this paper. A copy of each U.S. and foreign patent, or each publication or portion thereof listed or herein identified, is submitted herewith.

This Information Disclosure Statement is submitted within three months of the filing date of the above-captioned U.S. patent application. Accordingly, no fee is due or payable at this time.

The Examiner is requested to acknowledge consideration of the information provided in this paper in accordance with prescribed procedures.

Please charge any additional fees or credit any overpayments in connection with this paper to Deposit Account No. 08-1480.

Respectfully submitted,

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January 16, 2002

Form PTO 1449	ATTY. DOCKET NUMBER TSUT.0010	Serial Number To be assigned	PTO
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Information Disclosure Statement by Applicant	FILING DATE Concurrently Herewith	GROUP	10/01
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U.S. Patent Documents

Examiner	DOCUMENT	DATE	Name	CLASS	SUBC	FILING DATE
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Foreign Patent Documents

Exami	DOCUMENT NUMBER	FILING DATE	COUNTRY	CLASS	Sub-	Tran	SLATION
ner Initial					CLASS	YES	No

Other Documents (Including Author, Title, Date Pertinent Pages, Etc.)

Nick X. Sun, Alex Q. Huang and F.C. Lee, "0.35μm, 43 μΩcm ² power, 6 mΩ power MOSFET to power future microprocessor," 1999 IEEE, pp. 77-80
Wharton McDaniel, "MOSFET selection is key to successful DC-DC conversion," Supplement to Electronic Design, December 6, 1999, pp. 158-165
Edward Stanford, "Device requirements for future CPU voltage regulators," Intel. Corp., pp. 1-6

Examiner	DATE CONSIDERED

EXAMINER: Initial if citation is considered, whether or not citation is in conformance with MPEP 609; draw a line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant

PTO1449